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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Pan et al. Art Unit: 2812
Serial No.: 10/669,111 Examiner: Pompey, R.
Filing Date: 09/23/2003 Docket No.: TI-36040
Customer No.: 23494 Conf. No.: 3098
Title: DEPLETION DRAIN-EXTENDED MOS TRANSISTORS AND
METHODS FOR MAKING THE SAME

CERTIFICATION OF FACSIMILE TRANSMISSION

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U.S. Patent and Trademark Office at 703-872-9306 on the date shown below:


Jacqueline J. Garner, Reg. No. 36,144

June 13, 2005
Date

FACSIMILE COVER SHEET

<input checked="" type="checkbox"/> FACSIMILE COVER SHEET	<input checked="" type="checkbox"/> AMENDMENT (8 Pages)
<input type="checkbox"/> NEW APPLICATION	<input checked="" type="checkbox"/> EOT 3mth (3 Pages)
<input type="checkbox"/> DECLARATION (# Pages)	<input type="checkbox"/> NOTICE OF APPEAL (# Pages)
<input type="checkbox"/> ASSIGNMENT (# Pages)	<input type="checkbox"/> APPEAL (# Pages)
<input type="checkbox"/> FORMAL DRAWINGS	<input type="checkbox"/> ISSUE FEE (# Pages)
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<input type="checkbox"/> CONTINUATION APP'N (# Pages)	
<input type="checkbox"/> DIVISIONAL APP'N	
NAME OF INVENTOR(S): Pan	
TITLE OF INVENTION: Depletion Drain-Extended . . .	
TI FILE NO.: TI-36040	DEPOSIT ACCT. NO.: 20-0668
FAXED: 6/13/2005 DUE: 3/13/2005 ATTY/SEC'Y: JJG	
RECEIPT DATE & SERIAL NO.: Serial No.: 10/669,111 Filing Date: 9/23/2003 Conf. No.: 3098 RECEIVED OIPE/IAP JUN 14 2005	

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Serial No.:	10/669,111	Examiner:	Pompey, R.
Filing Date:	09/23/2003	Docket No.:	TI-36040
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Title: DEPLETION DRAIN-EXTENDED MOS TRANSISTORS AND METHODS FOR MAKING THE SAME			

AMENDMENT UNDER 37 CFR 1.111

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

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Jacqueline J. Garner
Reg. No. 36,144

Dear Sir:

The following amendments and remarks are offered in response to the Examiner's Office Action dated 12/13/2004. They are respectfully submitted as a full and complete response to that Action.

Please amend the above-referenced application as follows:

There are no **Amendments to the Specification**.

Amendments to the Claims are reflected in the listing of claims that begin on page 2 of this paper.

There are no **Amendments to the Drawings**.

The **Remarks** begin on page 6.